

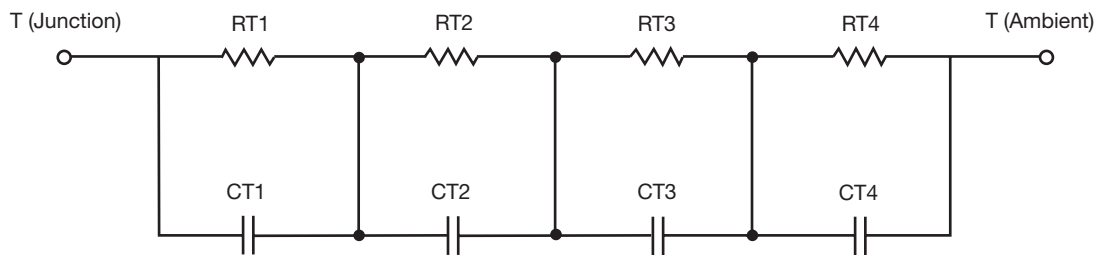
R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION

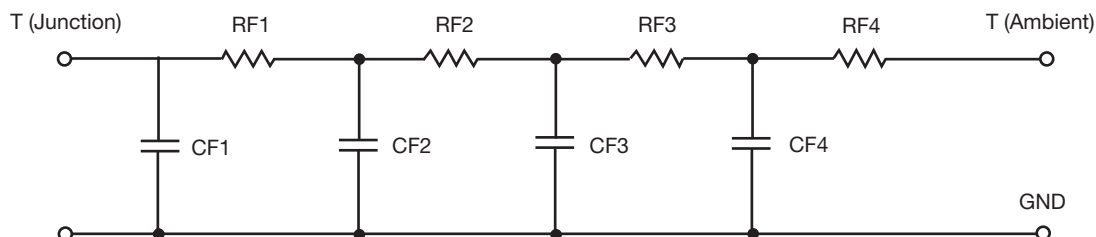


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	55.5474	N/A	11.4054
RT2	20.5045	N/A	5.4069
RT3	34.4088	N/A	1.0497
RT4	9.2383	N/A	19.9603
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	1.8266	N/A	13.6705 m
CT2	2.4408	N/A	8.0367 m
CT3	39.6228 m	N/A	4.1226 m
CT4	2.4286 m	N/A	61.4736 m

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION

R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	6.3710	N/A	1.1666
RF2	26.7613	N/A	17.7941
RF3	19.8290	N/A	7.5156
RF4	66.6294	N/A	11.3324
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	1.0603 m	N/A	718.7540 u
CF2	20.6997 m	N/A	4.4438 m
CF3	153.0634 m	N/A	45.7759 m
CF4	1.1714	N/A	17.6255 m

Note

N/A indicates not applicable

